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	Filing Date		2007-06-27	
	First Named Inventor	Koji Nakayama		
	Art Unit	2811		
	Examiner Name	Lynne Ann Gurley		
	Attorney Docket Number	1217-062849		

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	4	03038876	WO	A1	2003-05-08	Cree Inc.		<input type="checkbox"/>
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	2	LENDENMANN, H. ET AL., "High-Power SiC Diodes: Characteristics, Reliability and Relation to Material Defects", Materials Science Forum, Vols. 389-393 (2002), pp. 1259-1264, Trans Tech Publications, Switzerland	<input type="checkbox"/>
	3	LEE, K.S. ET AL., "Surface Preparation of 6H-Silicon Carbide Substrates for Growth of High-Quality SiC Epilayers", Materials Science Forum, Vols. 457-460 (2004), pp. 797-800	<input type="checkbox"/>

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